# **CE** CHENYI ELECTRONICS

## LL4148

### SMALL SIGNAL SWITCHING DIODE

#### **FEATURES**

- . Silicon epitaxial planar diode
- . Fast swithching diodes
- . 500mW power dissipation
- . The diode is also available in the DO-35 case with the type
- designation 1N4148

#### **MECHANICAL DATA**

. Case: MinMelf glass case(SOD- 80)

. Weight: Approx. 0.05gram

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

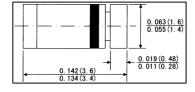
(Ratings at 25  $^\circ\!\!\!\mathrm{C}$  ambient temperature unless otherwise specified)

	Symbol	Value	Units
Reverse voltage	VR	75	Volts
Peak reverse voltage	Vrm	100	Volts
Average rectified current, Half wave rectification with	lav	1501)	mA
Resistive load at TA=25 $^{\circ}$ C and F $\geq$ 50Hz			
Surge forward current at t<1S and TJ=25 $^\circ\!\!\mathbb{C}$	IFSM	500	mA
Power dissipation at Ta=25℃	Ptot	5001)	mW
Junction temperature	TJ	175	°C
Storage temperature range	Tstg	-65 to + 175	°C

#### **ELECTRICAL CHARACTERISTICS**

(Ratings at 25  $^\circ\!\mathrm{C}$  ambient temperature unless otherwise specified)

	Symbols	Min.	Тур.	Max.	Units
Forward voltage	VF			1	Volts
Leakage current at VR=20V	lr			25	nA
at VR=75V	IR			5	nA
at VR=20V, TJ=150℃	lr			50	nA
Junction capacitance at VR=VF=0V	CJ			4	pF
Voltage rise when switching ON tested with 50mA	Vfr			2.5	Volts
pulse Tp=0.1 $\mu$ S, Rise time<30 $\mu$ S, fp=5 to 100KHz	VII				
Reverse recovery time from IF=10mA to IR=1mA,	trr			4	ns
VR=6V, RL=100 $\Omega$					
Thermal resistance junction to ambient	RθJA			3501)	K/W
Rectification efficience at f=100MHz,VRF=2V	η	0.45			
1)Valid provided that leads at a distance of 8mm from case	are kept at ambien	t temperature(l	DO-35)		



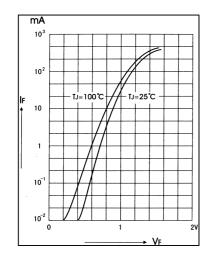
Dimensions in inches and (millimeters)

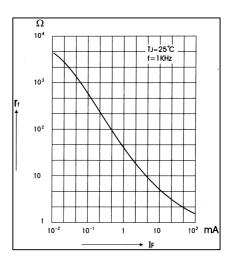
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## **RATINGS AND CHATACTERISTIC CURVES LL4148**

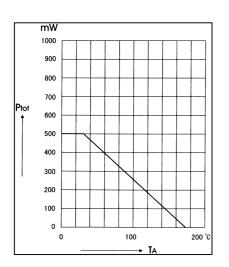
#### **FLG.1-FORWARD CHARACTERISTICS**

#### FIG.2-DYNAMIC FORWARD RESISTANCE VERSUS FORWARD CURRENT

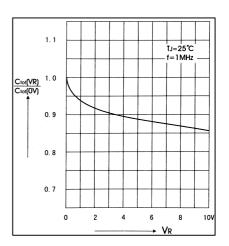




#### **FIG.3-ADMISSIBLE POWER DISSIPATION VERSUS AMBIENT TEMPERATURE**



#### **FIG.4-RELATIVE CAPACITANCE VERSUS** VOLTAGE

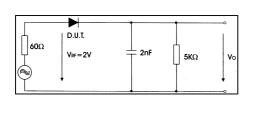


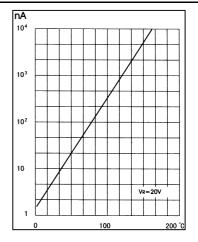


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#### FIG.5-RECTIFICATION EFFICIENCY MEASUREMENT CIRCUIT

#### FIG.6-LEAKAGE CURRENT VERSUS JUNCTION TEMPERATURE





#### FIG.7-ADMISSIBLE REPETITIVE PEAK FORWARD CURRENT VERSUS PULSE DURATION

